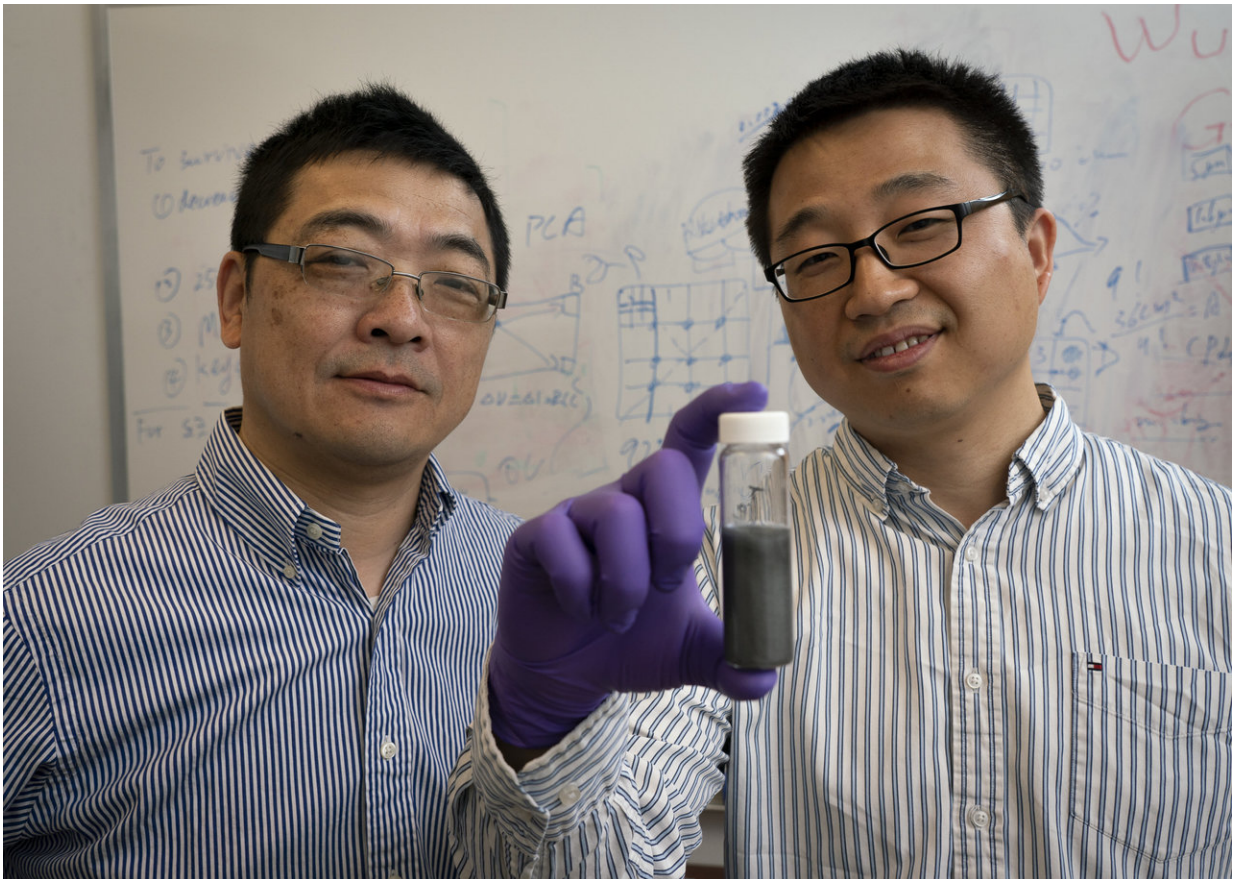


# Rare element to provide better material for high-speed electronics

May 24 2018, by Kayla Wiles

---



Purdue researchers Wenzhuo Wu and Peide Ye recently discovered tellurene, a two-dimensional material they manufactured in a solution, that has what it takes to make high-speed electronics faster. Credit: Purdue University image/Vincent Walter

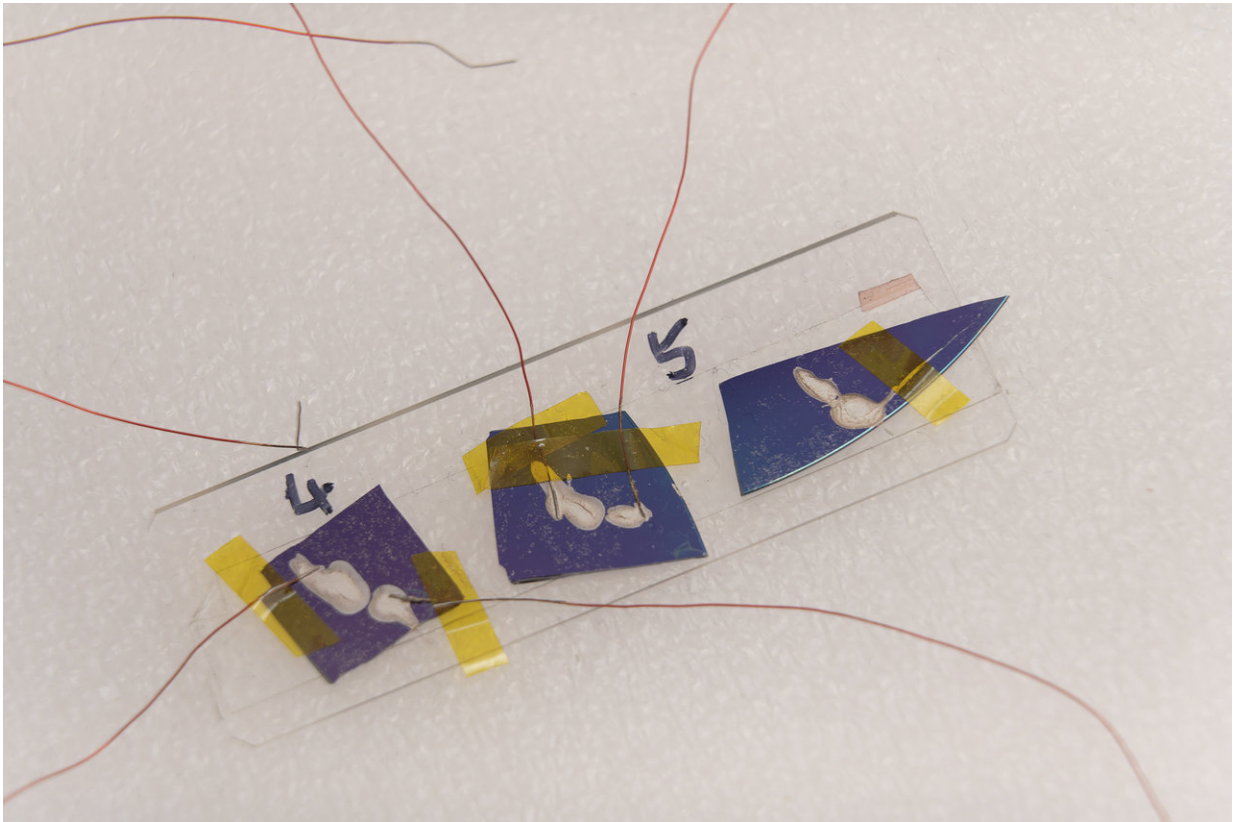
Purdue researchers have discovered a new two-dimensional material, derived from the rare element tellurium, to make transistors that carry a current better throughout a computer chip.

The discovery adds to a list of extremely thin, [two-dimensional materials](#) that engineers have tried to use for improving the operation speed of a chip's transistors, which then allows information to be processed faster in electronic devices, such as phones and computers, and defense technologies like infrared sensors.

Other two-dimensional [materials](#), such as graphene, black phosphorus and silicene, have lacked either stability at room temperature or the feasible production approaches required to nanomanufacture effective transistors for higher speed devices.

"All transistors need to send a large current, which translates to high-speed electronics," said Peide Ye, Purdue's Richard J. and Mary Jo Schwartz Professor of Electrical and Computer Engineering. "One-dimensional wires that currently make up transistors have very small cross sections. But a two-dimensional material, acting like a sheet, can send a current over a wider surface area."

Tellurene, a two-dimensional film researchers found in the element tellurium, achieves a stable, sheet-like transistor structure with faster-moving "carriers"—meaning electrons and the holes they leave in their place. Despite tellurium's rarity, the pros of tellurene would make transistors made from two-dimensional materials easier to produce on a larger scale. The researchers detail their findings in *Nature Electronics*.



A small quantity of two-dimensional tellurene, derived from the rare element tellurium, can make computer chip transistors both more scalable and efficient. Credit: Purdue University image/Vincent Walter

"Even though tellurium is not abundant on the Earth's crust, we only need a little bit to be synthesized through a solution method. And within the same batch, we have a very high production yield of two-dimensional tellurene materials," said Wenzhuo Wu, assistant professor in Purdue's School of Industrial Engineering. "You simply scale up the container that holds the solution, so productivity is high."

Since electronics are typically in use at room temperature, naturally stable tellurene transistors at this temperature are more practical and cost-effective than other two-dimensional materials that have required a

vacuum chamber or low operation temperature to achieve similar stability and performance.

The larger crystal flakes of tellurene also mean less barriers between flakes to electron movement—an issue with the more numerous, smaller flakes of other two-dimensional materials.

"High carrier mobility at [room temperature](#) means more practical applications," Ye said. Faster-moving electrons and holes then lead to higher currents across a chip.

The researchers anticipate that because tellurene can grow on its own without the help of any other substance, the material could possibly find use in other applications beyond computer chip [transistors](#), such as flexible printed devices that convert mechanical vibrations or heat to electricity.

"Tellurene is a multifunctional material, and Purdue is the birthplace for this new material," Wu said. "In our opinion, this is much closer to the scalable production of two-dimensional materials with controlled properties for practical technologies."

**More information:** Yixiu Wang et al, Field-effect transistors made from solution-grown two-dimensional tellurene, *Nature Electronics* (2018). [DOI: 10.1038/s41928-018-0058-4](https://doi.org/10.1038/s41928-018-0058-4)

Provided by Purdue University

Citation: Rare element to provide better material for high-speed electronics (2018, May 24) retrieved 22 March 2023 from <https://phys.org/news/2018-05-rare-element-material-high-speed-electronics.html>

This document is subject to copyright. Apart from any fair dealing for the purpose of private study or research, no part may be reproduced without the written permission. The content is provided for information purposes only.